

October 2009

# FJAF4310 NPN Epitaxial Silicon Transistor

## **Features**

- · Audio Power Amplifier
- High Current Capability : I<sub>C</sub>=10A
- · High Power Dissipation
- Wide S.O.A
- Complement to FJAF4210



# **Absolute Maximum Ratings\*** $T_A=25$ °C unless otherwise noted

| Symbol           | Parameter                                    | Value      | Units |
|------------------|--|------------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage                       | 200        | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage                    | 140        | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage                         | 6          | V     |
| I <sub>C</sub>   | Collector Current (DC)                       | 10         | Α     |
| I <sub>B</sub>   | Base Current (DC)                            | 1.5        | Α     |
| P <sub>C</sub>   | Collector Dissipation (T <sub>C</sub> =25°C) | 80         | W     |
| $R_{\theta JC}$  | Junction to Case                             | 1.48       | °C/W  |
| T <sub>J</sub>   | Junction Temperature                         | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature                          | - 55 ~ 150 | °C    |

# $\textbf{Electrical Characteristics} \quad \textbf{T}_{A} = 25 ^{\circ} \textbf{C} \text{ unless otherwise noted}$

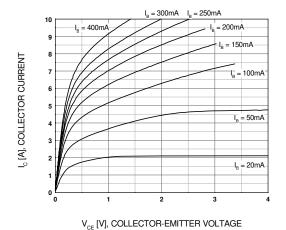
| Symbol                | Parameter                            | Test Condition                           | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|--|------|------|------|-------|
| BV <sub>CBO</sub>     | Collector-Base Breakdown Voltage     | I <sub>C</sub> =5mA, I <sub>E</sub> =0   | 200  |      |      | V     |
| BV <sub>CEO</sub>     | Collector-Emitter Breakdown Voltage  | $I_C$ =50mA, $R_{BE}$ = $\infty$         | 140  |      |      | V     |
| BV <sub>EBO</sub>     | Emitter-Base Breakdown Voltage       | I <sub>E</sub> =5mA, I <sub>C</sub> =0   | 6    |      |      | V     |
| I <sub>CBO</sub>      | Collector Cut-off Current            | V <sub>CB</sub> =200V, I <sub>E</sub> =0 |      |      | 10   | μΑ    |
| I <sub>EBO</sub>      | Emitter Cut-off Current              | V <sub>EB</sub> =6V, I <sub>C</sub> =0   |      |      | 10   | μА    |
| h <sub>FE</sub>       | * DC Current Gain                    | V <sub>CE</sub> =4V, I <sub>C</sub> =3A  | 50   |      | 180  |       |
| V <sub>CE</sub> (sat) | Collector-Emitter Saturation Voltage | I <sub>C</sub> =5A, I <sub>B</sub> =0.5A |      |      | 0.5  | V     |
| C <sub>ob</sub>       | Output Capacitance                   | V <sub>CB</sub> =10V, f=1MHz             |      | 250  |      | pF    |
| f <sub>T</sub>        | Current Gain Bandwidth Product       | $V_{CE}=5V$ , $I_{C}=1A$                 |      | 30   |      | MHz   |

<sup>\*</sup> Pulse Test : PW=20µs

## **h**<sub>FE</sub> Classification

| · <del>-</del>  |          |          |          |
|-----------------|----------|----------|----------|
| Classification  | R        | 0        | Y        |
| h <sub>FE</sub> | 50 ~ 100 | 70 ~ 140 | 90 ~ 180 |

## **Typical Perpormance Characteristics**



02

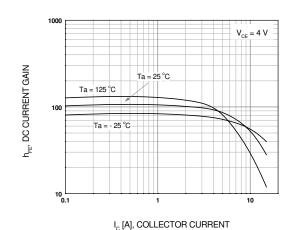


Figure 2. DC current Gain



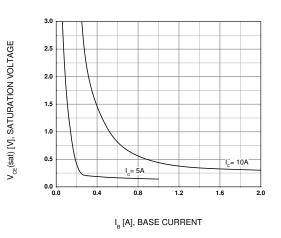


Figure 3. V<sub>CE</sub>(sat) vs. I<sub>B</sub> Characteristics

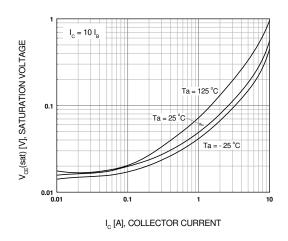


Figure 4. Collector-Emitter Saturation Voltage

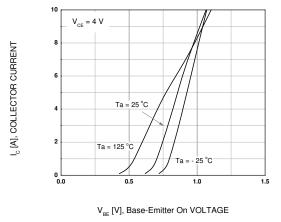


Figure 5. Base-Emitter On Voltage

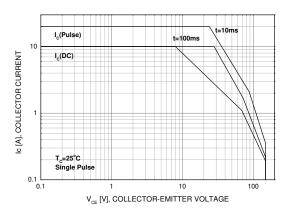


Figure 6. Forward Bias Safe Operating Area

# **Typical Perpormance Characteristics**

(Continued)

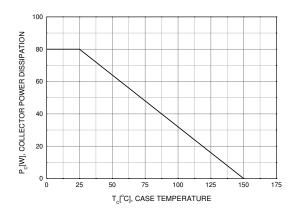
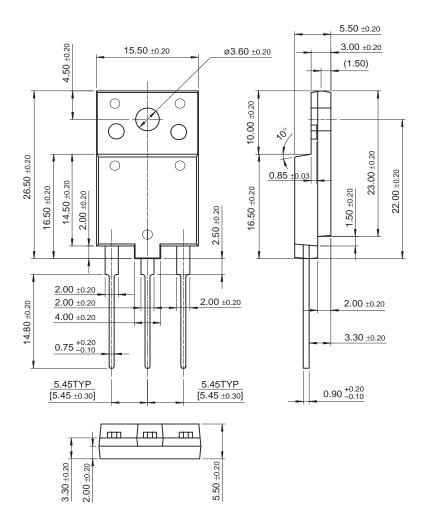


Figure 7. Power Derating

## **Physical Dimension**

# TO-3PF



Dimensions in Millimeters





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